

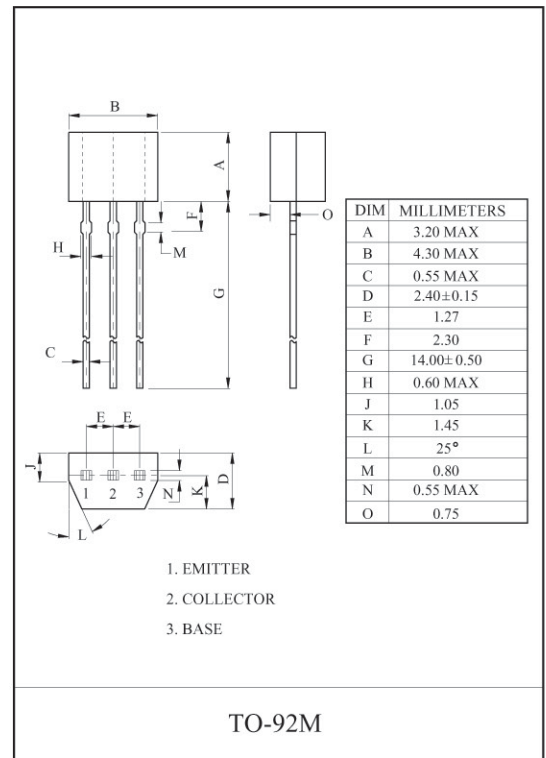
HIGH CURRENT APPLICATION.

#### FEATURES

- Complementary to KTA1272.

#### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	35	V
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	800	mA
Emitter Current	$I_E$	-800	mA
Collector Power Dissipation	$P_C$	400	mW
Junction Temperature	T	150	°C
Storage Temperature Range	$T_{stg}$	-55 ~ 150	°C



#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=30V$ $I_E=0$	-	-	100	nA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=5V$ $I_C=0$	-	-	100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10mA$ $I_B=0$	30	-	-	V
DC Current Gain	$f_{E(1)}$ (Note)	$V_{CE}=1V$ $I_C=100mA$	100	-	320	
	$f_{E(2)}$	$V_{CE}=1V$ $I_C=700mA$	35	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500mA$ $I_B=-20mA$	-	-	0.5	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE}=1V$ $I_C=10mA$	0.5	-	0.8	V
Transition Frequency	$f_T$	$V_{CE}=5V$ $I_C=10mA$	-	120	-	MH
Collector Output Capacitance	$C_o$	$V_{CB}=10V$ $I_E=0$ $f=1MHz$	-	13	-	pF

Note :  $f_{E(1)}$  Classification 0:100 ~ 200 Y:160 ~ 320